





#### 15V NPN LOW SATURATION TRANSISTOR

### **Features and Benefits**

- BV<sub>CEO</sub> > 15V
- I<sub>C</sub> = 4.5A Continuous Collector Current
- Low Saturation Voltage (100mV max @ 1A)
- R<sub>SAT</sub> = 45 mΩ for a low equivalent On-Resistance
- h<sub>FE</sub> specified up to 12A for high current gain hold up
- Low profile 0.6mm high package for thin applications
- R<sub>0</sub>JA efficient, 60% lower than SOT23
- 4mm<sup>2</sup> footprint, 50% smaller than SOT23
- Lead-Free, RoHS Compliant (Note 1)
- Halogen and Antimony Free. "Green" Device (Note 2)
- Qualified to AEC-Q101 Standards for High Reliability

### **Mechanical Data**

- Case: DFN2020B-3
- Case Material: Molded Plastic. "Green" Molding Compound.
- Terminals: Pre-Plated NiPdAu leadframe.
- Nominal Package Height: 0.6mm
- UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Weight: 0.01 grams (approximate)

## **Applications**

- MOSFET Gate Driving
- DC-DC Converters
- Charging Circuits
- Motor Control
- Power switch

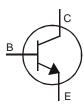
#### DFN2020B-3



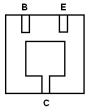




**Bottom View** 



Device Symbol



Bottom View Pin-Out

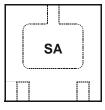
## **Ordering Information**

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXTN617MATA	SA	7	8	3000

Notes:

- 1. No purposefully added lead.
- Diodes Inc's "Green" Policy can be found on our website at http://www.diodes.com.

# **Marking Information**



Top View

SA = Product Type Marking code



# Maximum Ratings @TA = 25°C unless otherwise specified

Characteristic		Symbol	Value	Unit		
Collector-Base Voltage		V <sub>CBO</sub>	40			
Collector-Emitter Voltage		$V_{CEO}$	15	7 v		
Emitter-Base Voltage		V <sub>EBO</sub>	7	1		
Peak Pulse Current		I <sub>CM</sub>	15			
Continuous Collector Current	(Note 3)	1-	4.5	_		
Continuous Collector Current	(Note 4)	Ic	5	A		
Base Current		I <sub>B</sub>	1			

## Thermal Characteristics @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit		
Power Dissipation	(Note 3)		1.5 12	W	
Linear Derating Factor	(Note 4)	P <sub>D</sub>	2.45 19.6	mW/°C	
Thermal Resistance, Junction to Ambient	(Note 3)	D	83		
Thermal Resistance, Junction to Ambient	(Note 4)	$R_{ heta JA}$	51	°C/W	
Thermal Resistance, Junction to Lead (Note 5)		$R_{ hetaJL}$	16.8	I	
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C		

#### Notes:

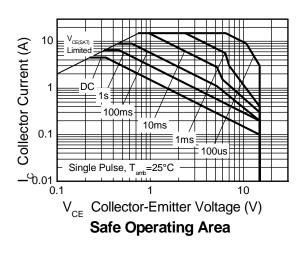
- 3. For a device surface mounted on 31mm x 31mm (10cm<sup>2</sup>) FR4 PCB with high coverage of single sided 1oz copper, in still air conditions; the device is measured when operating in a steady-state condition. The entire exposed collector pad is attached to the heatsink.

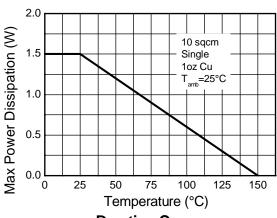
  4. Same as note (3), except the device is measured at t ≤ 5 sec.

  5. For a single device, thermal resistance from junction to solder-point (at the end of the drain lead).



## **Thermal Characteristics**





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100m

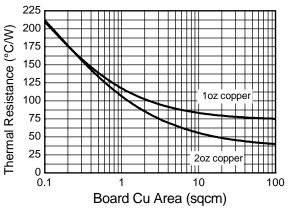
Pulse Width (s)

10

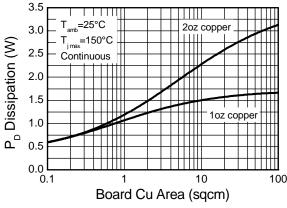
100

1k

**Derating Curve** 



### **Transient Thermal Impedance**



Thermal Resistance v Board Area

**Power Dissipation v Board Area** 

100µ





## Electrical Characteristics @T<sub>A</sub> = 25°C unless otherwise specified

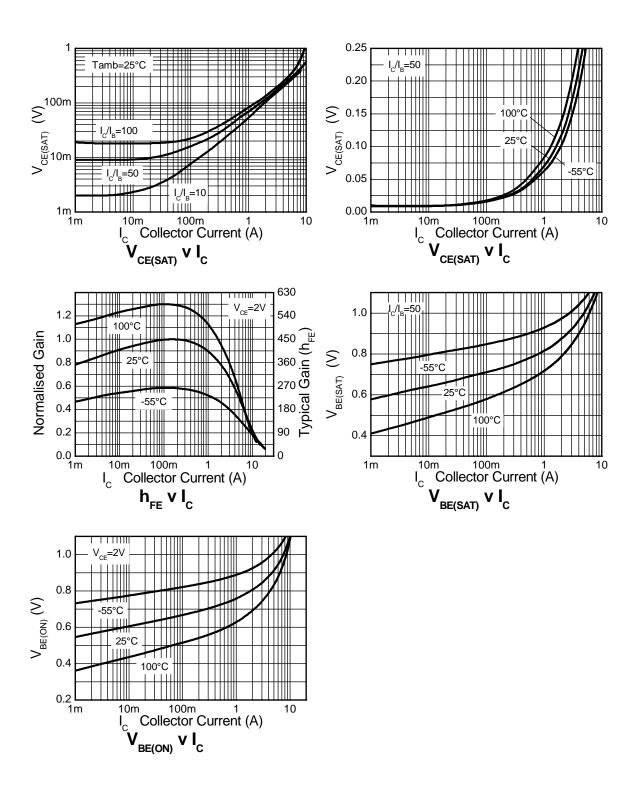
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	$BV_CBO$	40	70	-	V	I <sub>C</sub> = 100 μA
Collector-Emitter Breakdown Voltage (Note 6)	BV <sub>CEO</sub>	15	18	-	V	I <sub>C</sub> = 10 mA
Emitter-Base Breakdown Voltage	$BV_EBO$	7	8.2	-	V	I <sub>E</sub> = 100 μA
Collector Cutoff Current	I <sub>CBO</sub>	-	-	100	nA	V <sub>CB</sub> = 30V
Emitter Cutoff Current	I <sub>EBO</sub>	-	-	100	. nA	V <sub>EB</sub> = 6V
Collector Emitter Cutoff Current	I <sub>CES</sub>	-	-	100	nA	V <sub>CES</sub> = 12V
Static Forward Current Transfer Ratio (Note 6)	h <sub>FE</sub>	200 300 200 150	415 450 320 240 80	- - - -	-	$\begin{split} &I_{C} = 10\text{mA}, \ V_{CE} = 2V \\ &I_{C} = 200\text{mA}, \ V_{CE} = 2V \\ &I_{C} = 3\text{A}, \ V_{CE} = 2V \\ &I_{C} = 5\text{A}, \ V_{CE} = 2V \\ &I_{C} = 12\text{A}, \ V_{CE} = 2V \end{split}$
Collector-Emitter Saturation Voltage (Note 6)	V <sub>CE(sat)</sub>	- - - -	8 70 165 240 200	14 100 200 310	mV	$I_{C}$ =0.1A, $I_{B}$ = 10mA $I_{C}$ = 1A, $I_{B}$ = 10mA $I_{C}$ = 3A, $I_{B}$ = 50mA $I_{C}$ =4.5A, $I_{B}$ = 50mA $I_{C}$ =4.5A, $I_{B}$ = 100mA
Base-Emitter Turn-On Voltage (Note 6)	V <sub>BE(on)</sub>	-	0.88	0.96	V	I <sub>C</sub> = 4.5A, V <sub>CE</sub> = 2V
Base-Emitter Saturation Voltage (Note 6)	V <sub>BE(sat)</sub>	-	0.94	1.05	V	$I_C = 4.5A$ , $I_B = 50mA$
Output Capacitance	C <sub>obo</sub>	-	30	40	pF	V <sub>CB</sub> = 10V. f = 1MHz
Transition Frequency	f⊤	80	120	-	MHz	V <sub>CE</sub> = 10V, I <sub>C</sub> = 50mA, f = 100MHz
Turn-On Time	t <sub>on</sub>	-	120	-	ns	V <sub>CC</sub> = 10V, I <sub>C</sub> = 1A
Turn-Off Time	t <sub>off</sub>	-	160	-	ns	$I_{B1} = I_{B2} = 10 \text{mA}$

Notes: 6. Measured under pulsed conditions. Pulse width  $\leq$  300  $\mu$ s. Duty cycle  $\leq$  2%.



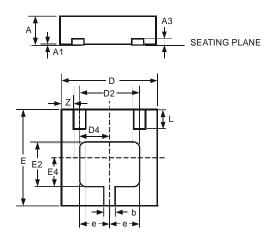


## **Typical Electrical Characteristics**



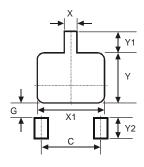


# Package Outline Dimensions



DFN2020B-3					
Dim	Min	Max	Тур		
Α	0.57	0.63	0.60		
A1	0	0.05	0.02		
A3	_	_	0.152		
b	0.20	0.30	0.25		
D	1.95	2.075	2.00		
D2	1.22	1.42	1.32		
D4	0.56	0.76	0.66		
е	_	_	0.65		
Е	1.95	2.075	2.00		
E2	0.79	0.99	0.89		
E4	0.48	0.68	0.58		
L	0.25	0.35	0.30		
Z	_	_	0.225		
All Dimensions in mm					

# **Suggested Pad Layout**



Dimensions	Value (in mm)		
С	1.30		
G	0.24		
Х	0.35		
X1	1.52		
Υ	1.09		
Y1	0.47		
Y2	0.50		





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